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|  | <h2>SIHP12N60E-E3</h2> |
| | <p>Hersteller-Teilenummer: SIHP12N60E-E3</p> <p>Hersteller / Marke: Electro-Films (EFI) / Vishay</p> <p>Teil der Beschreibung: MOSFET N-CH 600V 12A TO220AB</p> <p>Datenblätter: 1.SIHP12N60E-E3.pdf 2.SIHP12N60E-E3.pdf</p> <p>RoHs Status: Bleifrei / RoHS-konform</p> <p>Lagerzustand: New original, 1670 pcs Stock Available.</p> <p>Liefern von: Hong Kong</p> <p>Versandweg: DHL/Fedex/TNT/UPS/EMS</p> |
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| <p>Image may be representation. See specs for product details.</p> | |

Spezifikationen

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| Teilenummer | SIHP12N60E-E3 |
| Hersteller | Electro-Films (EFI) / Vishay |
| Beschreibung | MOSFET N-CH 600V 12A TO220AB |
| Kategorie | Diskrete Halbleiterprodukte > Transistoren-FETs, |
| Teilstatus | 1670 pcs Stock |
| detaillierte Beschreibung | N-Channel 600V 12A (Tc) 147W (Tc) Through Hole |
| Serie | - |
| Technologie | MOSFET (Metal Oxide) |
| Betriebstemperatur | -55°C ~ 150°C (TJ) |
| Befestigungsart | Through Hole |
| Verpackung / Gehäuse | TO-220-3 |
| Supplier Device-Gehäuse | TO-220AB |
| Verlustleistung (max) | 147W (Tc) |
| Typ FET | N-Channel |
| FET-Merkmal | - |
| Drain-Source-Spannung (Vdss) | 600V |
| Strom - Ununterbrochener Abfluss (Id) bei 25 ° C | 12A (Tc) |
| Rds On (Max) @ Id, Vgs | 380 mOhm @ 6A, 10V |
| VGS (th) (Max) @ Id | 4V @ 250µA |
| Gate Charge (Qg) (Max) @ Vgs | 58nC @ 10V |
| Eingabekapazität (Ciss) (Max) @ Vds | 937pF @ 100V |
| Antriebsspannung (Max Rds On, Min Rds On) | 10V |
| Vgs (Max) | ±30V |
| Verpackung | Tube |
| Bleifreier Status / RoHS-Status | Lead free / RoHS Compliant |
| Feuchtigkeitsempfindlichkeitsniveau (MSL) | 1 (Unlimited) |
| Andere Namen | SIHP12N60EE3 |

SIHP12N60E-E3 ist neu im Original. Suche SIHP12N60E-E3 Datenblätter, PDF, Inventar bei Y-IC.com Online, Bestellen Sie SIHP12N60E-E3 Electro-Films (EFI) / Vishay mit Garantie und Vertrauen. Anfrage SIHP12N60E-E3: Info@Y-IC.com

Sie können auch interessiert sein:

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|---|---|---|---|
|  <p>SIHP12N50E-GE3 Vishay / Siliconix MOSFET N-CH 500V 10.5A TO-220AB</p> |  <p>SIHP12N50E-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 500V 10.5A TO-220AB</p> |  <p>SIHP12N60E-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 600V 12A TO220AB</p> |  <p>SIHP12N65E-GE3 Electro-Films (EFI) / Vishay MOSFET N-CH 650V 12A TO-220AB</p> |
|  <p>SIHP12N65E VB SIHP12N65E VB</p> |  <p>SIHP12N60E-E3 Vishay / Siliconix MOSFET N-CH 600V 12A TO220AB</p> |  <p>SIHP12N60E-GE3 Vishay / Siliconix MOSFET N-CH 600V 12A TO220AB</p> |  <p>SIHP12N65E-GE3 Vishay / Siliconix MOSFET N-CH 650V 12A TO-220AB</p> |

heiße Teile

Mehr

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|----------------|----------------|----------------|----------------|-------------------|
| SIHFR9120T | SIHFR9220 | SIHFRC20 | SIHFR20TL-E3 | SIHFS11N50A |
| SIHFS9N60A | SIHFSL11N50A | SIHG16N50C-E3 | SIHG16N50C-E3 | SIHG17N60D |
| SIHG20N50C | SIHG22N60S-E3 | SIHG30N60E | SIHG33N60E | SIHG47N60E-E3 |
| SIHG47N60E-E3 | SIHG47N60E-GE3 | SIHG47N60E-GE3 | SIHG47N60S-E3 | SIHG70N60EFEF-GE3 |
| SIHG73N60E-GE3 | SIHG73N60E-GE3 | SIHP10N40D | SIHP12N50C-E3 | SIHP12N50C-E3 |
| SIHP12N60E-E3 | SIHP12N60E-GE3 | SIHP12N60E-GE3 | SIHP12N65E | SIHP14N50D |
| SIHP15N60E-E3 | SIHP15N60E-E3 | SIHP15N65E | SIHP16N50C-E3 | SIHP16N50C-E3 |
| SIHP17N60D-E3 | SIHP17N60D-E3 | SIHP18N50C-E3 | SIHP18N50C-E3 | SIHP22N60S-E3 |
| SIHP30N60E-E3 | SIHP30N60E-E3 | SIHP30N60E-GE3 | SIHP30N60E-GE3 | SIHP30N60E-GE3 |
| SIHP33N60E-GE3 | SIHP33N60E-GE3 | SIHP5N50D-E3 | SIHP5N50D-E3 | SIHP6N40D |

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